

TECHNICAL DATA
DATA SHEET 240, REV A.1**SILICON SCHOTTKY RECTIFIER DIE**
Ultra Low Reverse Leakage**Applications:**

- Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature²
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after packaging
- Out Performs 100 Volt Ultrafast Rectifiers

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	100	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form	16	A
Max. Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	10 ms, Sine pulse ⁽¹⁾	240	A
Non-Repetitive Avalanche Energy	E_{AS}	$T_J = 25\text{ }^{\circ}\text{C}$, $I_{AS} = 0.6\text{ A}$, $L = 30\text{ mH}$	8.8	mJ
Repetitive Avalanche Current	I_{AR}	I_{AS} decay linearly to 0 in $1\text{ }\mu\text{s}$ f limited by T_J max $V_A=1.5V_R$	0.6	A
Max. Junction Temperature	T_J	-	-55 to +175	$^{\circ}\text{C}$
Max. Storage Temperature	T_{stg}	-	-55 to +175	$^{\circ}\text{C}$

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 16A, Pulse, $T_J = 25\text{ }^{\circ}\text{C}$	0.85	V
	V_{F2}	@ 16A, Pulse, $T_J = 125\text{ }^{\circ}\text{C}$	0.69	V
Max. Reverse Current	I_{R1}	@ $V_R = 100\text{ V}$, Pulse, $T_J = 25\text{ }^{\circ}\text{C}$	10	μA
	I_{R2}	@ $V_R = 100\text{ V}$, Pulse, $T_J = 125\text{ }^{\circ}\text{C}$	1.0	mA
Max. Junction Capacitance	C_T	@ $V_R = 5\text{ V}$, $T_C = 25\text{ }^{\circ}\text{C}$ $f_{SIG} = 1\text{ MHz}$, $I_{SIG} = 50\text{ mV (p-p)}$	500	pF

(1) in SHD package

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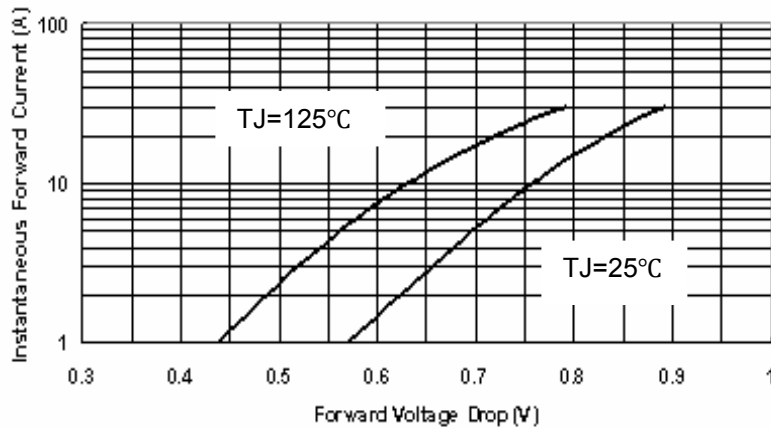


Fig.1-Typical Instantaneous Forward Voltage Characteristics

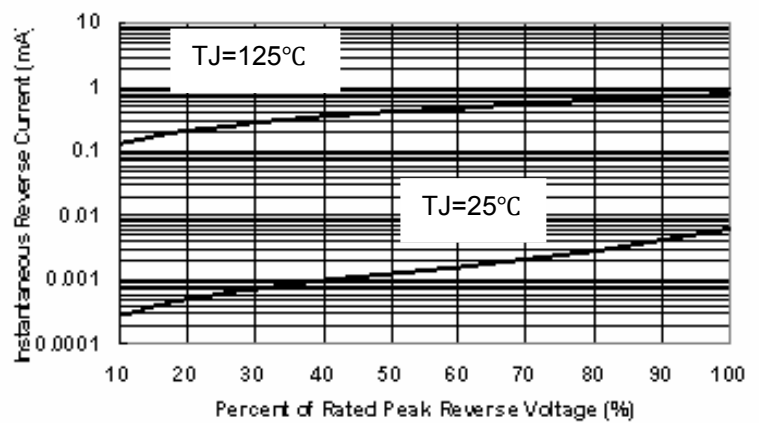


Fig.2-Typical Reverse Characteristics

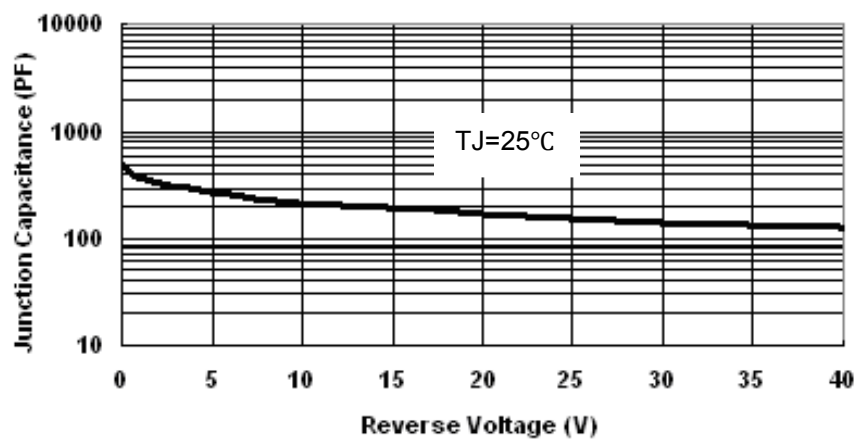


Fig.3 -Typical Junction Capacitance

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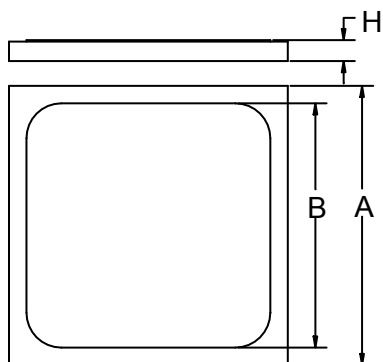
Mechanical Outline

Figure 1

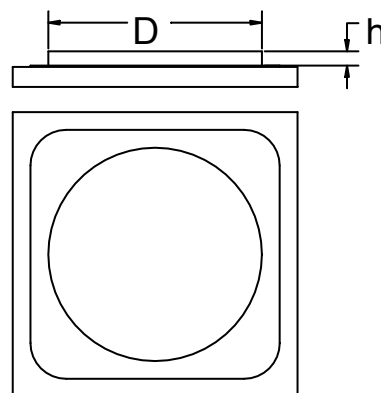


Figure 2

A	B	D	H	h
0.125±0.003	0.116±0.003	0.070±0.005	0.0155±0.001	0.010±0.002

Top side (Anode) metallization:

A = Al - 25 kÅ minimum, Figure 1

B = Ag - 30 kÅ minimum, Figure 1

C = Au - 12 kÅ min, Figure 2

Bottom side (Cathode) metallization:

A, B, C = Ti/Ni/Ag - 30 kÅ minimum.

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